

**MPSA06**  
Rev.E Mar.-2016

TO-92          NPN

Silicon NPN transistor in a TO-92 Plastic Package.

$V_{CE0}$       80V  
 $V_{CE0} < 80V. (I_C = 1mA).$

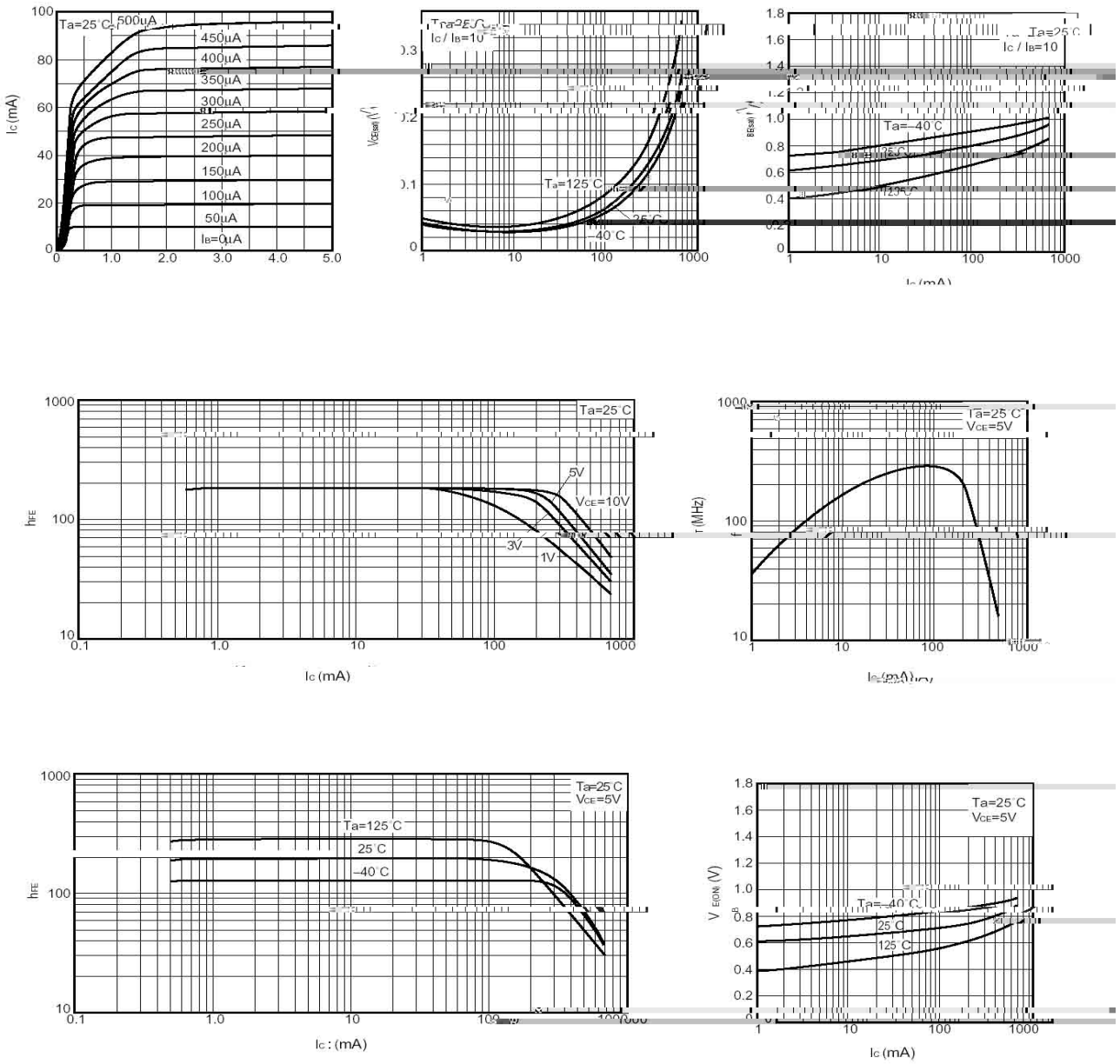
**/ Absolute Maximum Ratings(Ta=25 )**

Parameter	Symbol	Rating	Unit
Collector to Base Voltage	$V_{CBO}$	80	V
Collector to Emitter Voltage	$V_{CEO}$	80	V
Emitter to Base Voltage	$V_{EBO}$	5	V
Collector Current - Continuous	$I_C$	500	mA
Peak Collector Current	$I_{CM}$	1	A
Peak Base Current	$I_{BM}$	200	mA
Collector Power Dissipation	$P_C$	625	mW
Junction Temperature	$T_j$	150	
Storage Temperature Range	$T_{stg}$	-55 150	

**/ Electrical Characteristics(Ta=25 )**

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Collector Cut-Off Current	$I_{CBO}$	$V_{CB}=80V$ $I_E=0$			0.05	$\mu A$
Emitter Cut-Off Current	$I_{EBO}$	$V_{EB}=5$ $I_C=0$			0.05	$\mu A$
DC Current Gain	$h_{FE(1)}$	$V_{CE}=1V$ $I_C=100mA$	100			
	$h_{FE(2)}$	$V_{CE}=1V$ $I_C=10mA$	100			
Collector to Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=100mA$ $I_B=10mA$			0.25	V
Base to Emitter Voltage	$V_{BE}$	$V_{CE}=1V$ $I_C=100mA$			1.2	V
Transition Frequency	$f_T$	$V_{CE}=2V$ $I_C=10mA$ $f=100MHz$	100			MHz

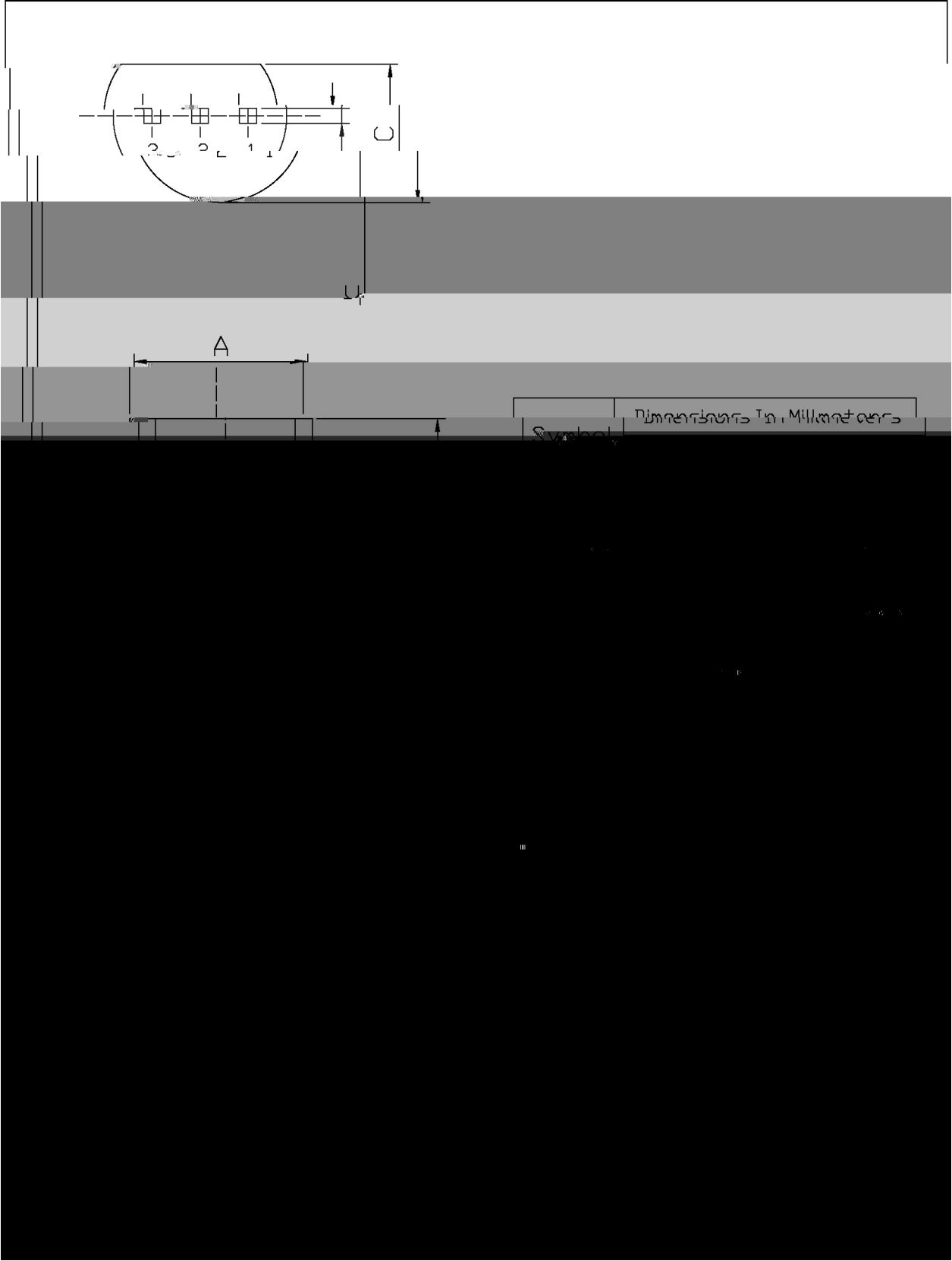
**/ Electrical Characteristic Curve**



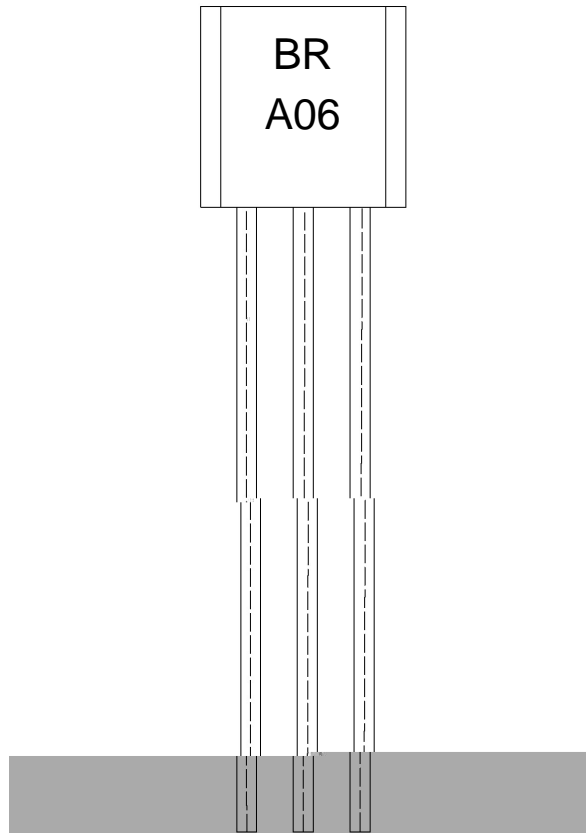
/ Package Dimensions

T0-92

Unit: mm



/ Marking Instructions



BR:

A06

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Note:

BR:           Company Code.

A06:          Product Type.

\*\*\*\*:         Lot No. Code,code change with Lot No.

